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7.0 V to 26.0 V Input, 1 A Integrated MOSFET Single Synchronous Buck DC/DC Converter

BD9E104FJ

General Description

BD9E104FJ is a synchronous buck DC/DC converter with built-in low on-resistance power MOSFETs. High efficiency at light load with a SLLM™ (Simple Light Load Mode). It is most suitable for use in the equipment to reduce the standby power is required. It is a current mode control DC/DC converter and features high-speed transient response. Phase compensation can also be set easily.

Features

- SLLM™ Control (Simple Light Load Mode)
- Single Synchronous Buck DC/DC converter
- Over Current Protection
- Short Circuit Protection
- Thermal Shutdown Protection
- Under Voltage Lockout Protection
- Internal Soft Start
- Reduce External Diode
- SOP-J8 Package

Applications

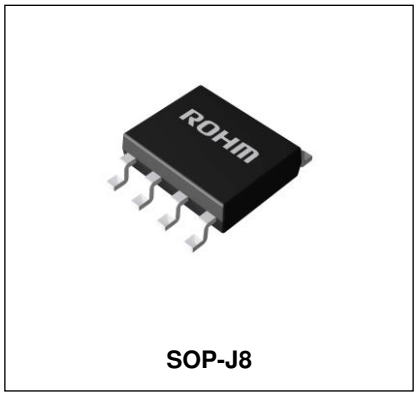
- Consumer Applications such as Home Appliance
- Secondary Power Supply and Adapter Equipment
- Telecommunication Devices

Key Specifications

- Input Voltage Range: 7.0 V to 26.0 V
- Output Voltage Range: 1.0 V to V_{IN} x 0.5 V
- Output Current: 1.0 A (Max)
- Switching Frequency: 570 kHz (Typ)
- High Side MOSFET ON-Resistance: 250 mΩ (Typ)
- Low Side MOSFET ON-Resistance: 200 mΩ (Typ)
- Shutdown Current: 0 µA (Typ)

Package

	W(Typ) x D(Typ) x H(Max)
SOP-J8	4.90mm x 6.00mm x 1.65mm



SOP-J8

Typical Application Circuit

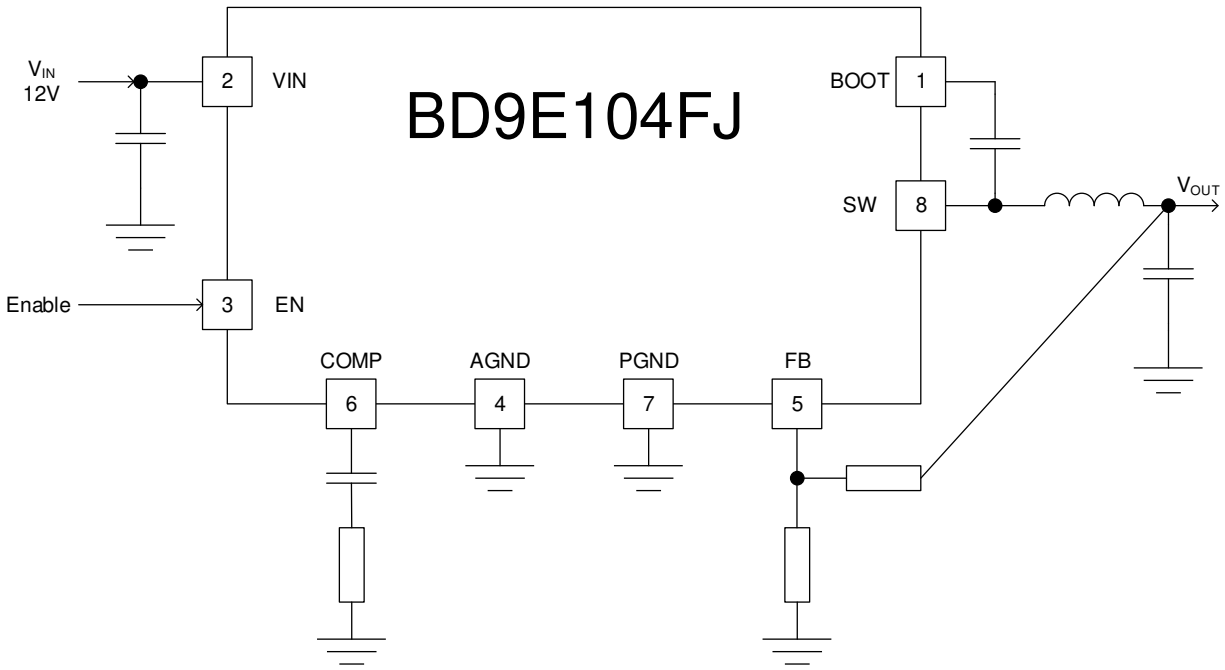


Figure 1. Application Circuit

SLLM™ is a trademark of ROHM Co., Ltd.

○Product structure : Silicon monolithic integrated circuit ○This product has no designed protection against radioactive rays

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Pin Configuration

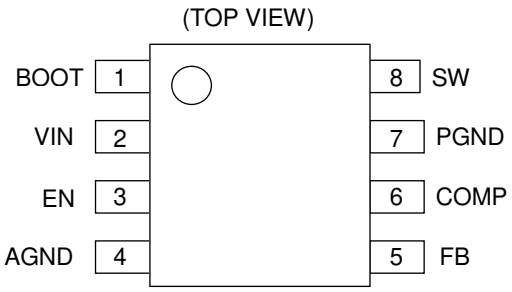

Figure 2. Pin Configuration

Pin Descriptions

Pin No.	Pin Name	Description
1	BOOT	Connect a bootstrap capacitor of 0.1 µF between this pin and the SW pin. The voltage of this capacitor is the gate drive voltage of the High Side MOSFET.
2	VIN	Power supply pin for the switching regulator and control circuit. Connecting a 10 µF ceramic capacitor is recommended.
3	EN	Turning this pin signal low-level (0.8 V or lower), the device is forced to be in the shutdown mode. Turning this pin signal high-level (2.5 V or higher) enables the device. This pin must be terminated.
4	AGND	Ground pin for the control circuit.
5	FB	Inverting input node for the gm error amplifier. See page 21 for how to calculate the resistance of the output voltage setting.
6	COMP	Input pin for the gm error amplifier output and the output for the PWM comparator. Connect phase compensation components to this pin. See page 22 for how to calculate the resistance and capacitance for phase compensation.
7	PGND	Ground pin for the output stage of the switching regulator.
8	SW	Switch pin. This pin is connected to the source of the High Side MOSFET and drain of the Low Side MOSFET. Connect a bootstrap capacitor of 0.1 µF between this pin and the BOOT pin. In addition, connect an inductor considering the direct current superimposition characteristic.

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Block Diagram

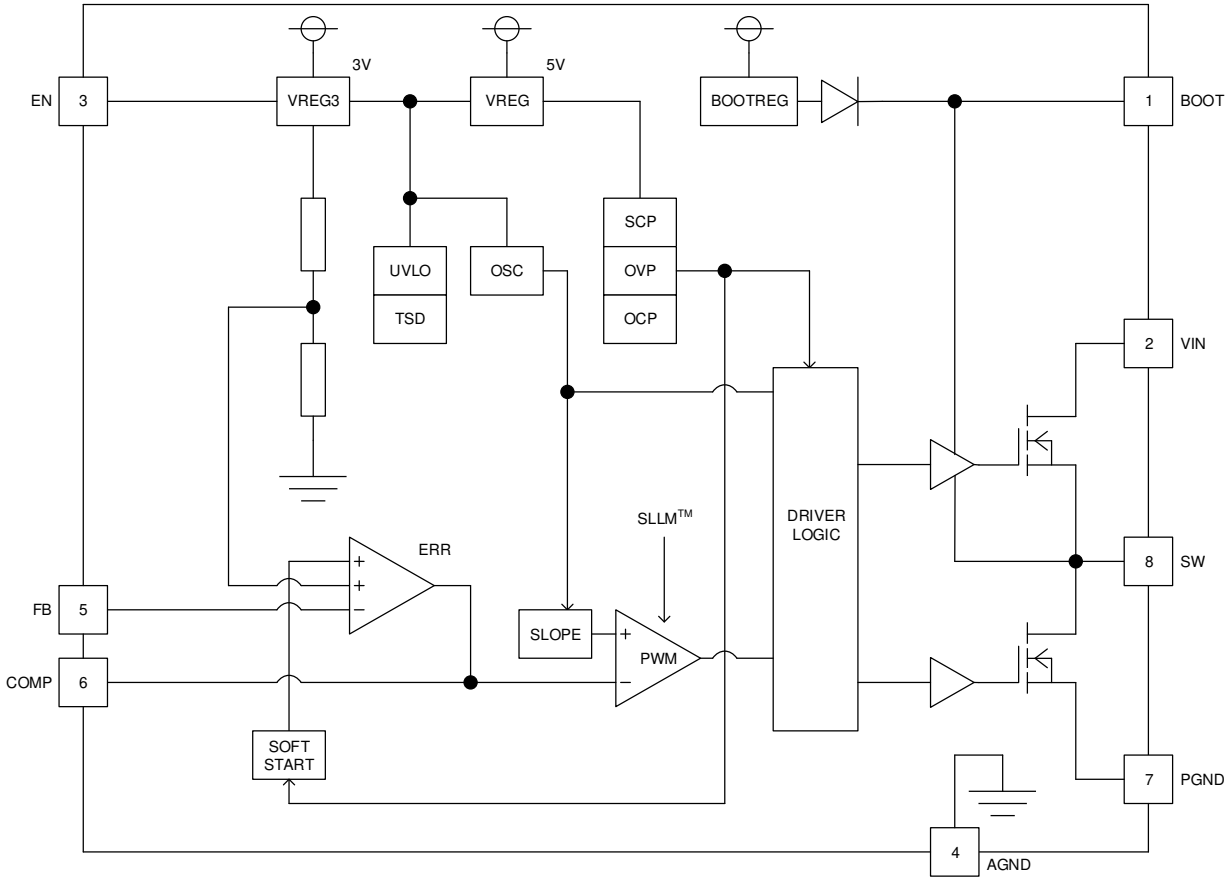

Figure 3. Block Diagram

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Description of Blocks

- VREG3
  Block creating internal reference voltage 3 V (Typ).

- VREG
  Block creating internal reference voltage 5 V (Typ).

- BOOTREG
  Block creating gate drive voltage.

- TSD
  The TSD block is for thermal protection. It shuts down the device when the internal temperature of IC rises to 175 °C (Typ) or higher. Thermal protection circuit resets when the temperature falls. The circuit has a hysteresis of 25 °C (Typ).

- UVLO
  This is under voltage lockout block. It shuts down the device when the VIN pin voltage falls to 6.4V (Typ) or less. The UVLO threshold voltage has a hysteresis of 200mV (Typ).

- ERR
  The ERR amplifier compares the reference voltage with the feedback voltage of the output voltage. The ERR amplifier output voltage (the COMP pin voltage) determine the switching duty. Also, the COMP pin voltage is limited by internal slope voltage due to soft start function during start-up.

- OSC
  Block generating oscillation frequency.

- SLOPE
  Creates delta wave from clock, generated by OSC, and sends voltage composed by current sense signal of High Side MOSFET and delta wave to PWM comparator.

- PWM
  Settles the switching duty by comparing the output COMP pin voltage of ERR amplifier and signal of SLOPE block.

- DRIVER LOGIC
  This is DC/DC driver block. Input signal from PWM and drives MOSFET.

- SOFT START
  By controlling current, output voltage starts calmly preventing over shoot of output voltage and inrush current.

- OCP
  Current flowing in High Side MOSFET is controlled one cycle each of switching frequency when over current occurs.

- SCP
  When the FB pin voltage has fallen below 0.56 V (Typ) and remained there for 0.9ms (Typ), SCP stops the operation for 14.4 ms (Typ) and subsequently initiates a restart.

- OVP
  When the FB pin voltage exceeds 1.04 V (Typ), it turns MOSFET of output part MOSFET OFF. After output voltage dropped, it returns to normal operation with hysteresis.

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Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Unit
Input Voltage	V_{IN}	-0.3 to +30.0	V
EN Pin Voltage	V_{EN}	-0.3 to +30.0	V
Voltage from GND to BOOT	V_{BOOT}	-0.3 to +35.0	V
Voltage from SW to BOOT	ΔV_{BOOT}	-0.3 to +7.0	V
FB Pin Voltage	V_{FB}	-0.3 to +7.0	V
COMP Pin Voltage	V_{COMP}	-0.3 to +7.0	V
SW Pin Voltage	V_{SW}	-0.5 to +30.0	V
Maximum Junction Temperature	Tjmax	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Caution 1: *Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.*

Caution 2: *Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, design a PCB boards with thermal resistance taken into consideration by increasing board size and copper area so as not to exceed the maximum junction temperature rating.*

Thermal Resistance*(Note 1)*

Parameter	Symbol	Thermal Resistance (Typ)		Unit
		1s*(Note 3)*	2s2p*(Note 4)*	
SOP-J8				
Junction to Ambient	θ_{JA}	149.3	76.9	°C/W
Junction to Top Characterization Parameter*(Note 2)*	Ψ_{JT}	18	11	°C/W

(Note 1) Based on JESD51-2A(Still-Air)..
*(Note 2)*The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.
(Note 3) Using a PCB board based on JESD51-3.
(Note 4) Using a PCB board based on JESD51-7.

Layer Number of Measurement Board	Material	Board Size
Single	FR-4	114.3mm x 76.2mm x 1.57mmt

Top	
Copper Pattern	Thickness
Footprints and Traces	70µm

Layer Number of Measurement Board	Material	Board Size
4 Layers	FR-4	114.3mm x 76.2mm x 1.6mmt

Top		2 Internal Layers		Bottom	
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness
Footprints and Traces	70µm	74.2mm x 74.2mm	35µm	74.2mm x 74.2mm	70µm

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Recommended Operating Ratings

Parameter	Symbol	Rating			Unit
		Min	Typ	Max	
Input Voltage	V_{IN}	7.0	-	26.0	V
Operating Temperature	Topr	-40	-	+85 *(Note 1)*	°C
Output Current	I_{OUT}	-	-	1.0	A
Output Voltage Range	V_{RANGE}	1.0 *(Note 2)*	-	V_{IN}×0.5	V

(Note 1) Tj must be lower than 150°C under actual operating environment.
(Note 2) Please use it in output voltage setting of which output pulse width does not become 250 ns (Typ) or less.
See the page 21 for how to calculate the resistance of the output voltage setting.

Electrical Characteristics (Unless otherwise specified Ta=25°C, V_{IN}=12V, V_{EN}=3V)

Parameter	Symbol	Limits			Unit	Conditions
		Min	Typ	Max		
Operating Supply Current	I_{OPR}	-	250	500	µA	V_{FB}=0.9 V
Shutdown Current	I_{SD}	-	0	10	µA	V_{EN}=0 V
FB Pin Voltage	V_{FB}	0.784	0.800	0.816	V	
FB Input Current	I_{FB}	-1	0	+1	µA	V_{FB}=0.8 V
Switching Frequency	f_{OSC}	484	570	656	kHz	
High Side MOSFET ON-Resistance	R_{ONH}	-	250	-	mΩ	I_{SW}=100 mA
Low Side MOSFET ON-Resistance	R_{ONL}	-	200	-	mΩ	I_{SW}=100 mA
Over Current limit *(Note 3)*	I_{LIMIT}	2.1	2.4	2.7	A	Without switching
UVLO Threshold Voltage	V_{UVLO}	6.1	6.4	6.7	V	V_{IN} falling
UVLO Hysteresis Voltage	$V_{UVLOHYS}$	100	200	300	mV	
EN ON Threshold Voltage	V_{ENH}	2.5	-	V_{IN}	V	
EN OFF Threshold Voltage	V_{ENL}	0	-	0.8	V	
EN Input Current	I_{EN}	2	4	8	µA	V_{EN}=3 V
Soft Start Time	t_{SS}	1.2	2.5	5.0	ms	

(Note 3) No tested on outgoing inspection.

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Typical Performance Curves

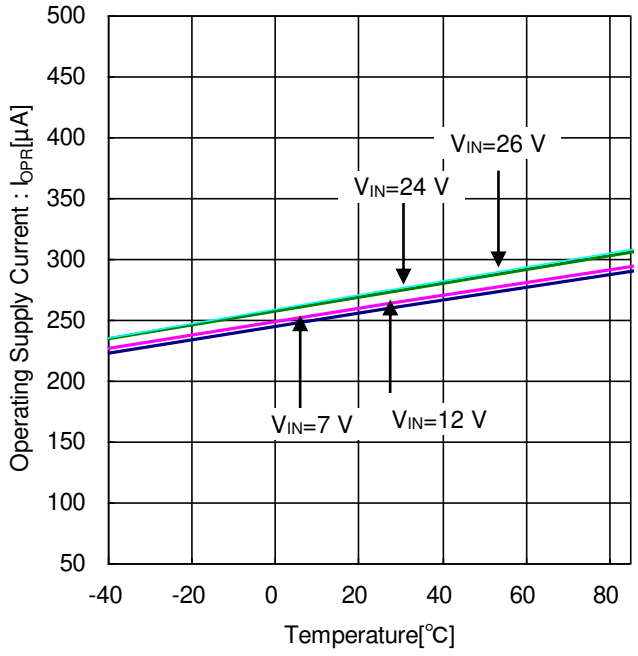

Figure 4. Operating Supply Current vs Temperature

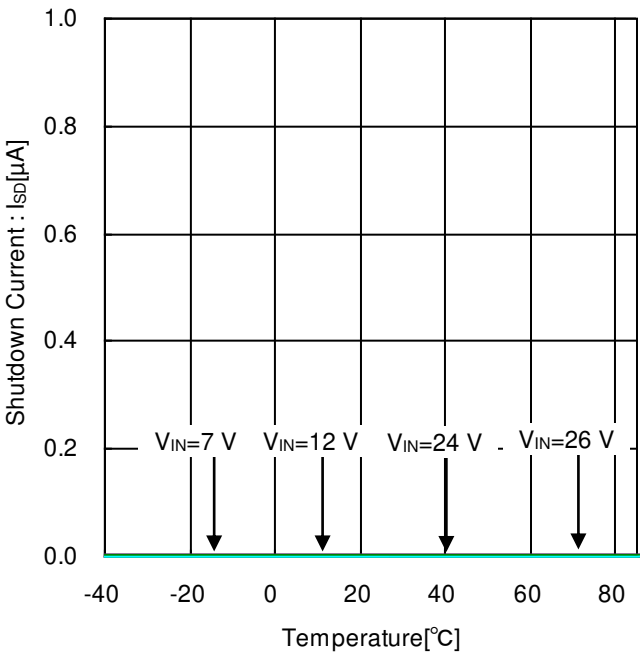

Figure 5. Shutdown Current vs Temperature

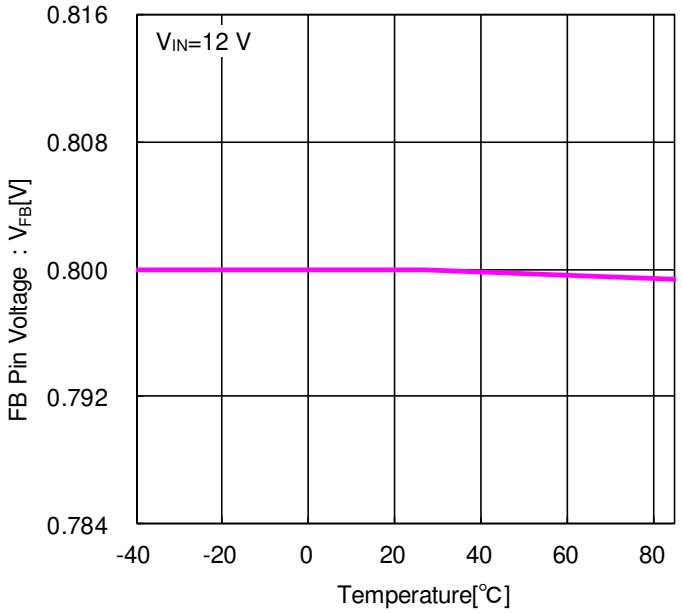

Figure 6. FB Pin Voltage vs Temperature

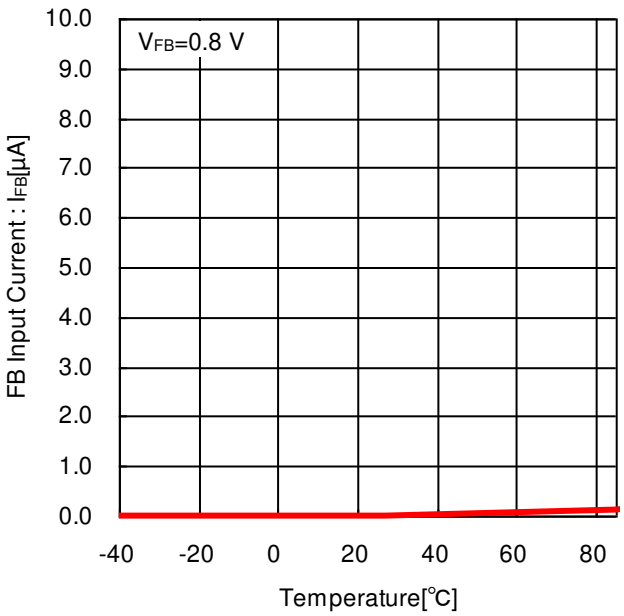

Figure 7. FB Input Current vs Temperature

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Typical Performance Curves - continued

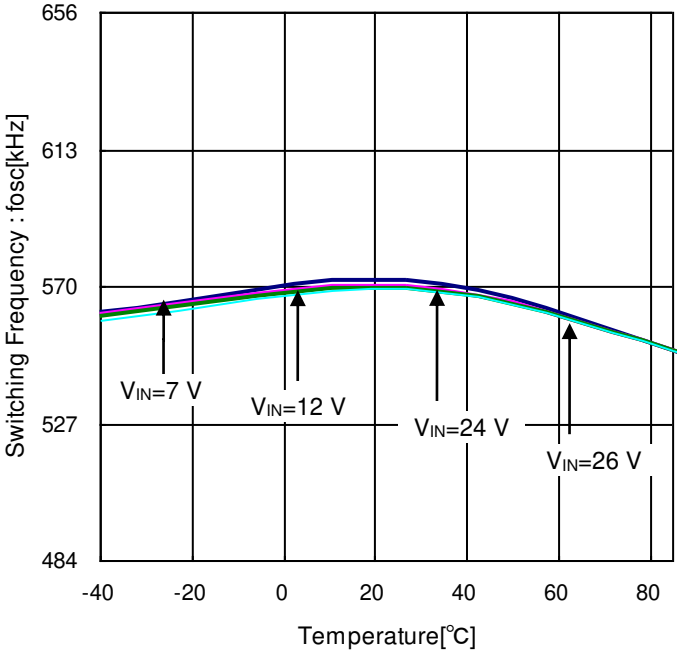

Figure 8. Switching Frequency vs Temperature

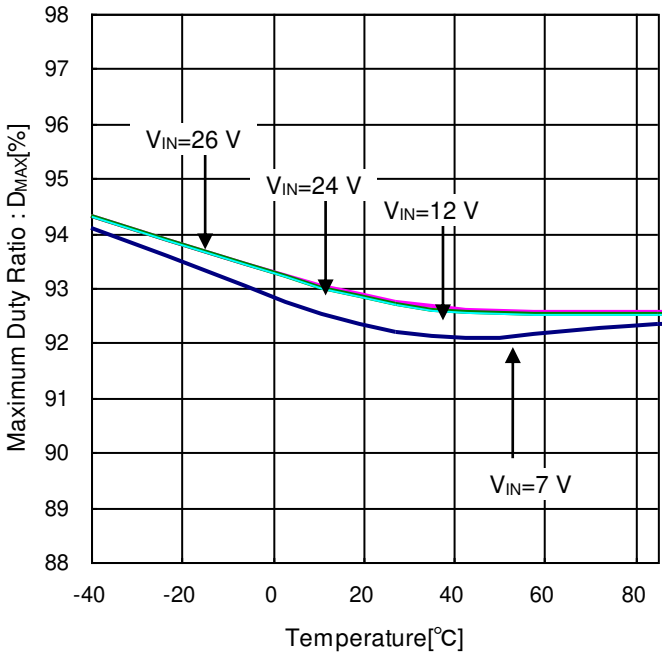

Figure 9. Maximum Duty Ratio vs Temperature

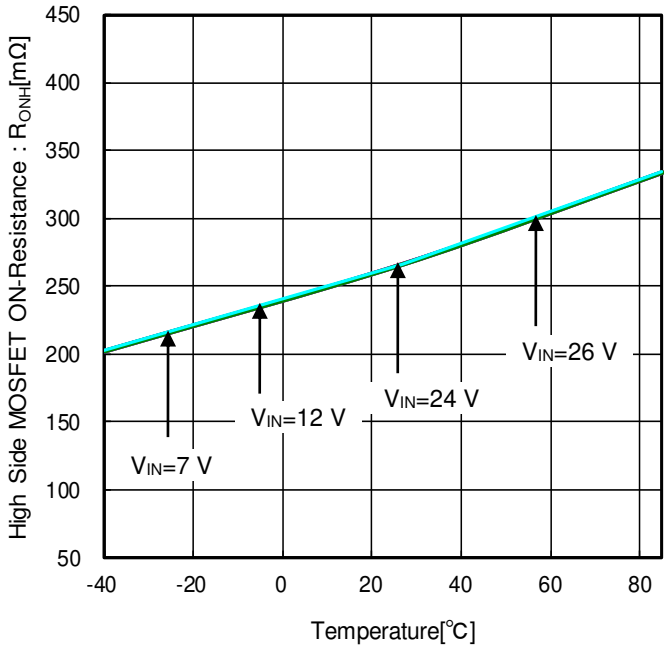

Figure 10. High Side MOSFET ON-Resistance vs Temperature

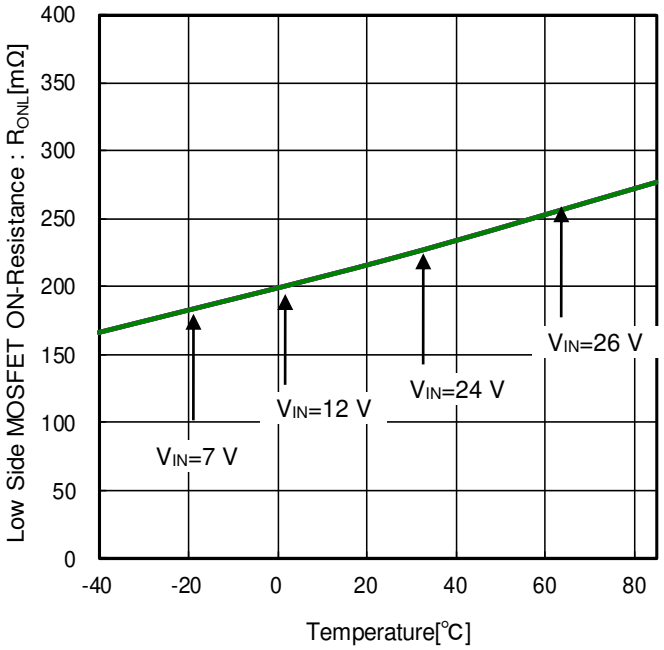

Figure 11. Low Side MOSFET ON-Resistance vs Temperature

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Typical Performance Curves - continued

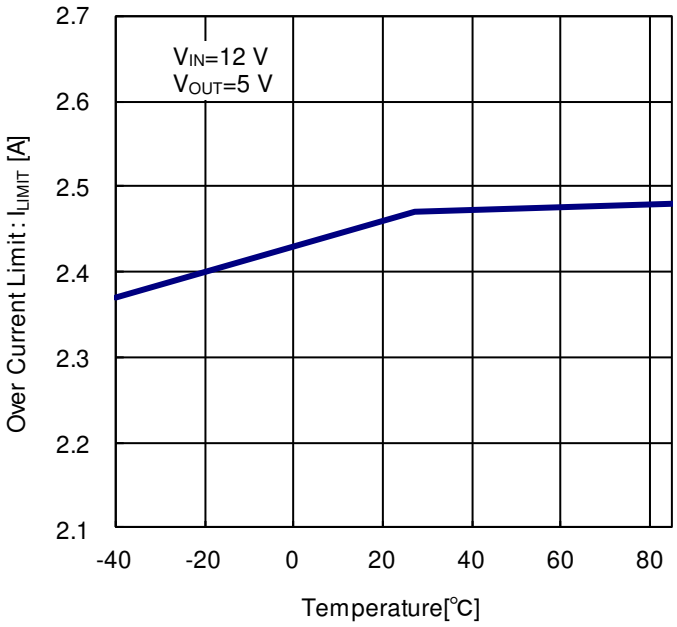

Figure 12. Over Current Limit vs Temperature

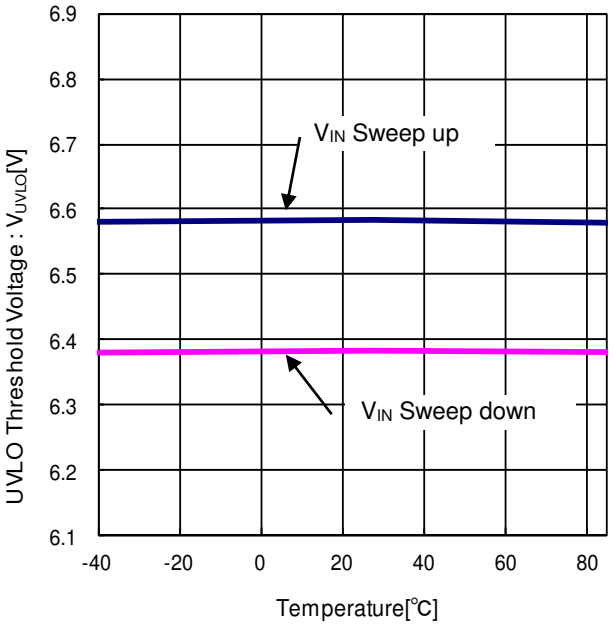

Figure 13. UVLO Threshold Voltage vs Temperature

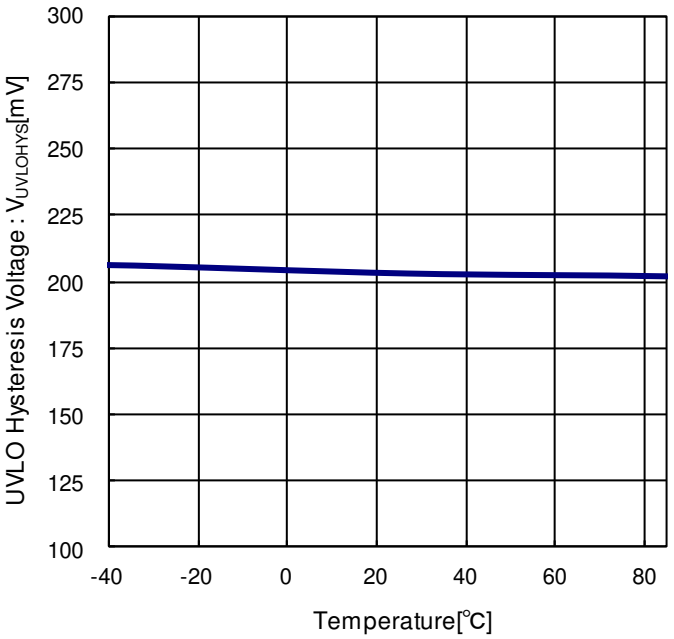

Figure 14. UVLO Hysteresis Voltage vs Temperature

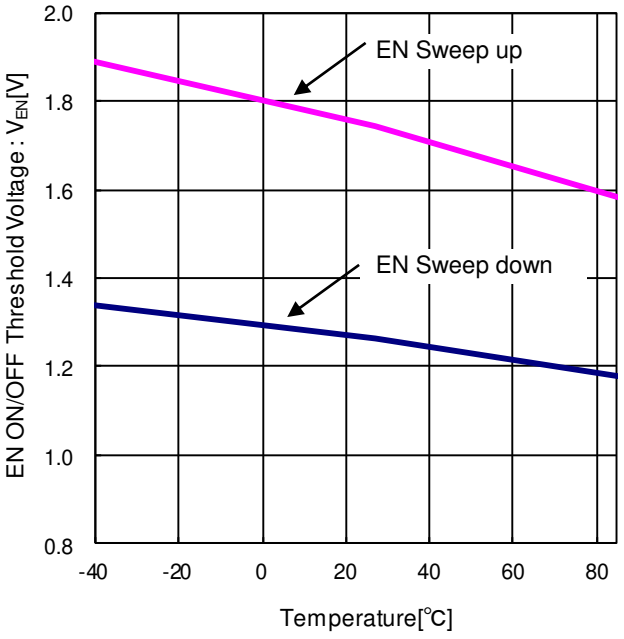

Figure 15. EN ON/OFF Threshold Voltage vs Temperature

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Typical Performance Curves - continued

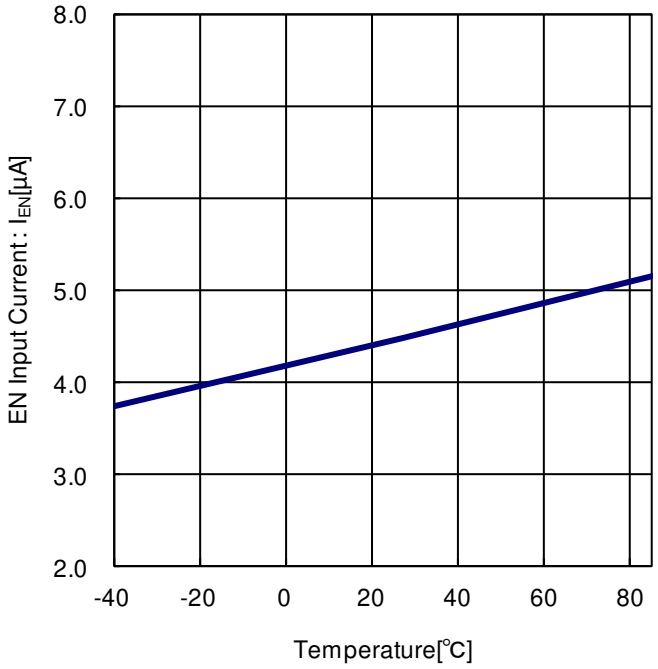

Figure 16. EN Input Current vs Temperature

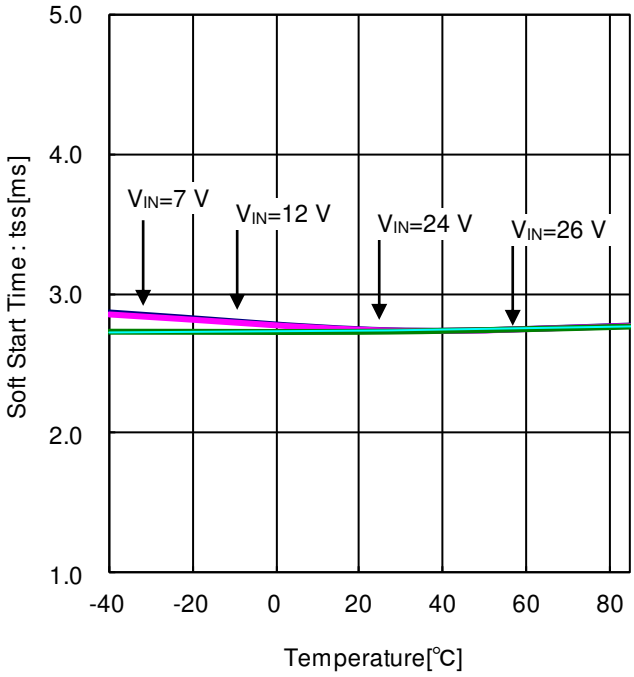

Figure 17. Soft Start Time vs Temperature

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Typical Performance Curves (Application)

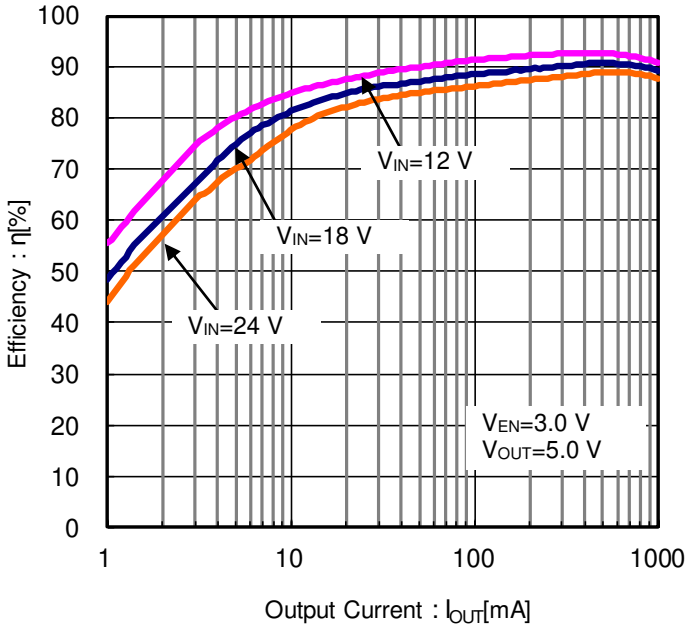

Figure 18. Efficiency vs Output Current
(V_{OUT}=5.0 V)

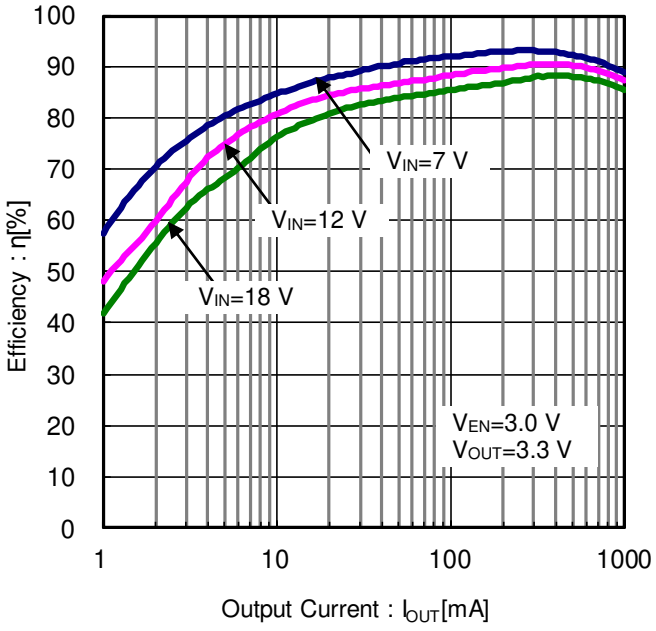

Figure 19. Efficiency vs Output Current
(V_{OUT}=3.3 V)

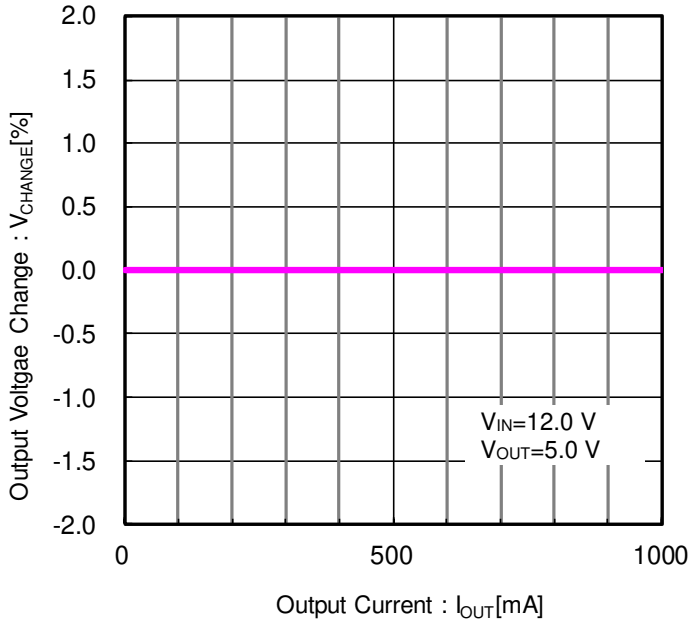

Figure 20. V_{OUT} Load Regulation

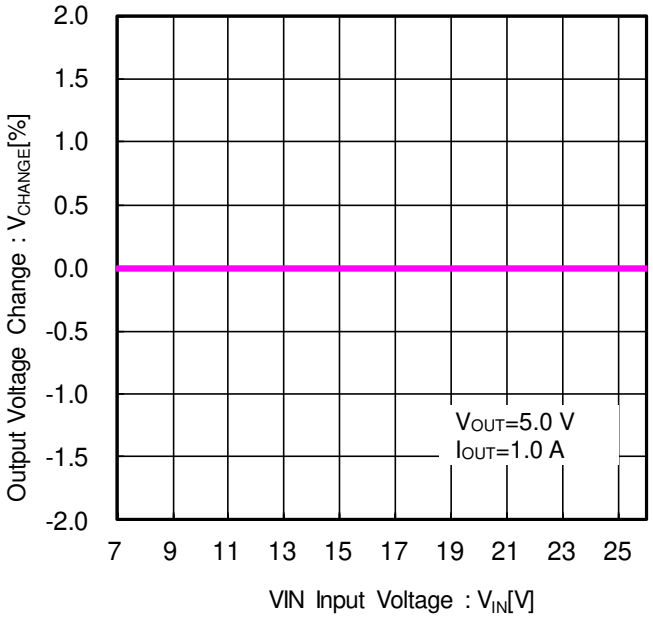

Figure 21. V_{OUT} Line Regulation

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Typical Performance Curves (Application) - continued

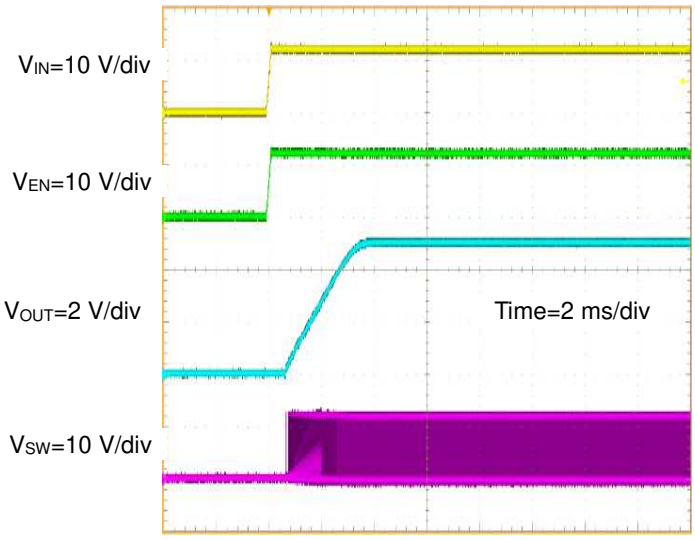

Figure 22. Start-up Waveform (V_{IN}=V_{EN})
I_{OUT}=1.0 A

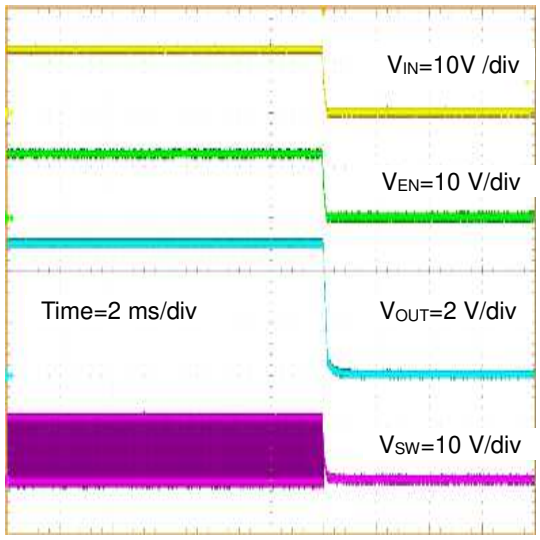

Figure 23. Shutdown Waveform (V_{IN}=V_{EN})
I_{OUT}=1.0 A

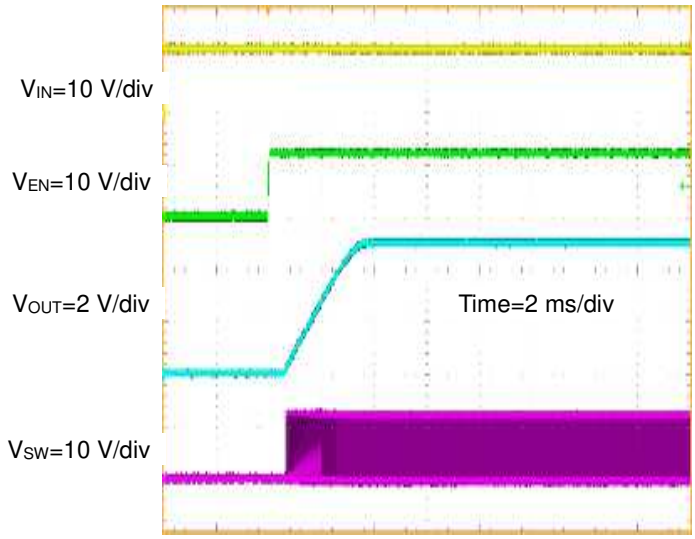

Figure 24. Start-up Waveform (V_{EN}=0 V to 5 V)
I_{OUT}=1.0 A

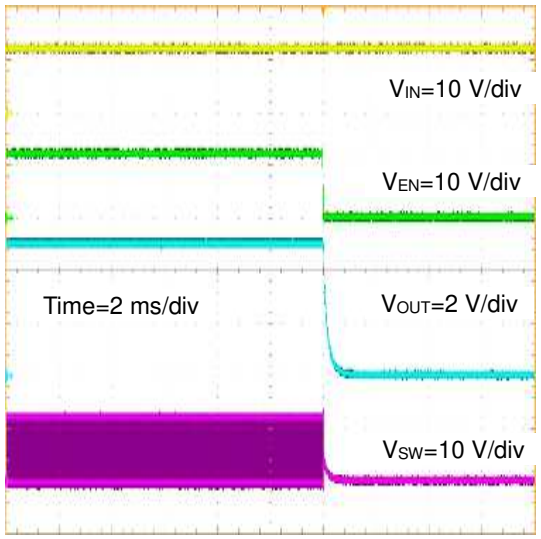

Figure 25. Shutdown Waveform (V_{EN}=5 V to 0 V)
I_{OUT}=1.0 A

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Typical Performance Curves (Application) - continued

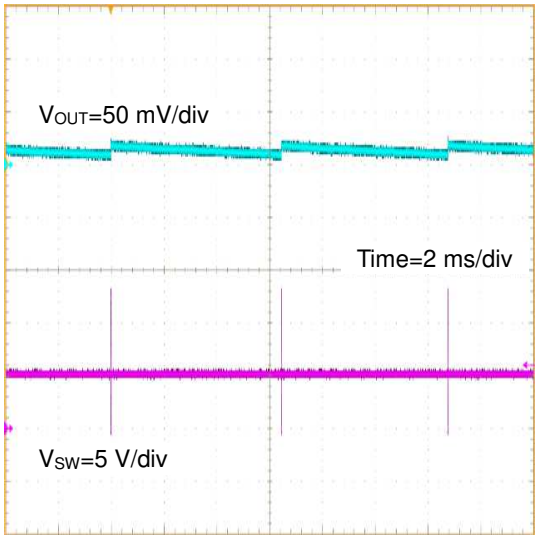

Figure 26. V_{OUT} Ripple
(V_{IN}=12 V, V_{OUT}= 5 V, I_{OUT}=0 A, C_{OUT}=10 µFx3)

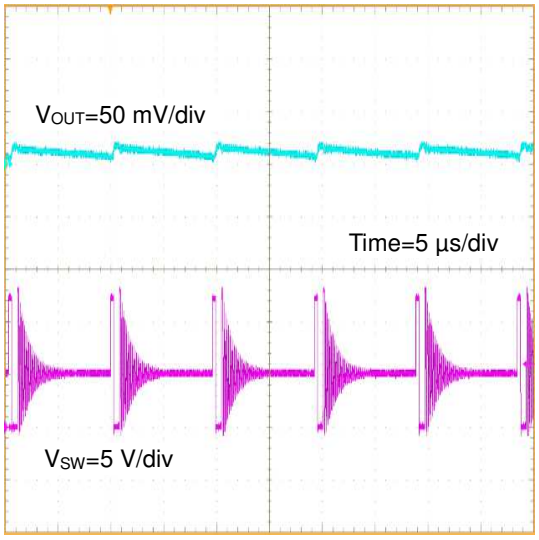

Figure 27. V_{OUT} Ripple
(V_{IN}=12 V, V_{OUT}=5 V, I_{OUT}=10 mA, C_{OUT}=10 µFx3)

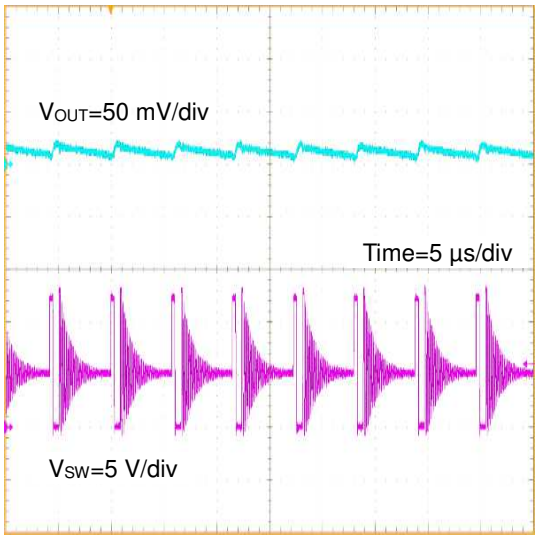

Figure 28. V_{OUT} Ripple
(V_{IN}=12 V, V_{OUT}=5 V, I_{OUT}=20 mA, C_{OUT}=10 µFx3)

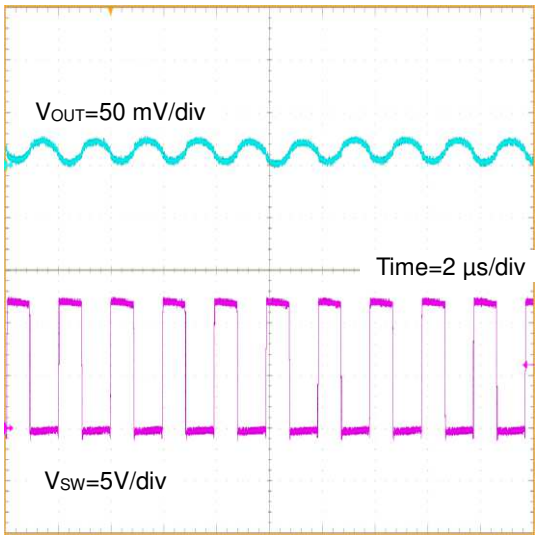

Figure 29. V_{OUT} Ripple
(V_{IN}=12 V, V_{OUT}=5 V, I_{OUT}=1 A, C_{OUT}=10 µFx3)

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Typical Performance Curves (Application) - continued

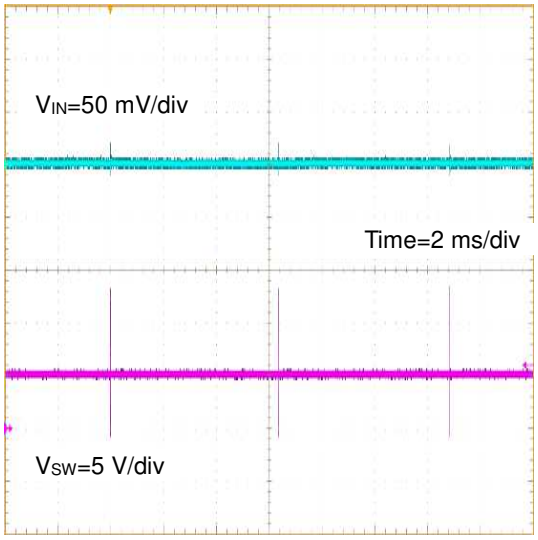

Figure 30. V_{IN} Ripple
(V_{IN}=12 V, V_{OUT}=5 V, I_{OUT}=0 A)

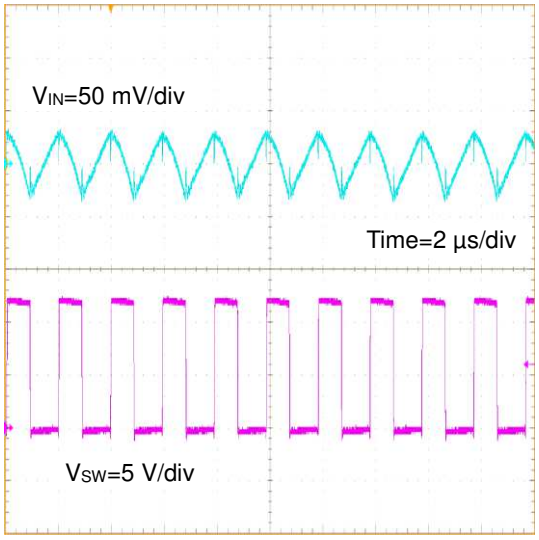

Figure 31. V_{IN} Ripple
(V_{IN}=12 V, V_{OUT}=5 V, I_{OUT}=1 A)

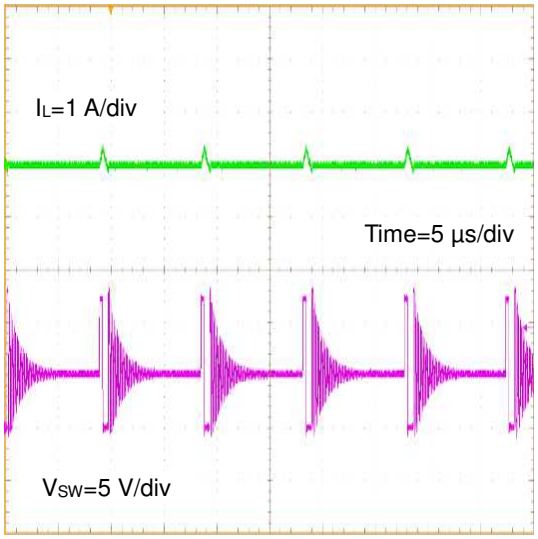

Figure 32. Switching Waveform
(V_{IN}=12 V, V_{OUT}=5 V, I_{OUT}=10 mA)

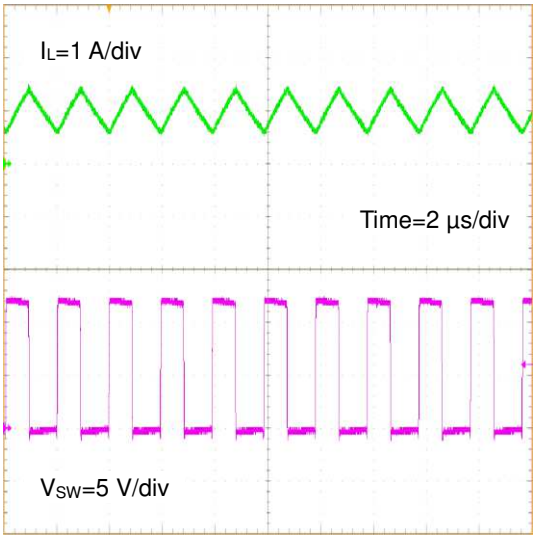

Figure 33. Switching Waveform
(V_{IN}=12 V, V_{OUT}=5 V, I_{OUT}=1 A)

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Typical Performance Curves (Application) - continued

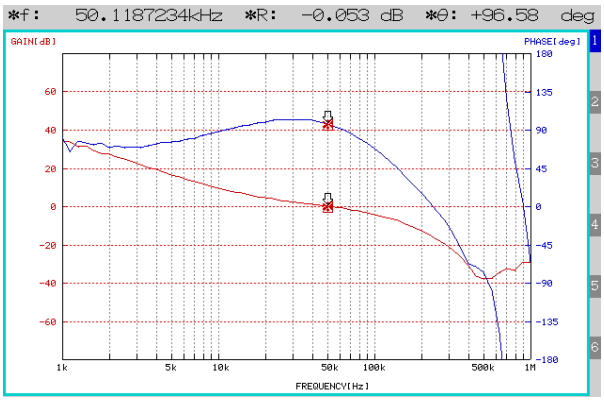

Figure 34. Loop Response
(V_{IN}=12 V, V_{OUT}=5 V, I_{OUT}=1 A, C_{OUT}=Ceramic10 µFx3)

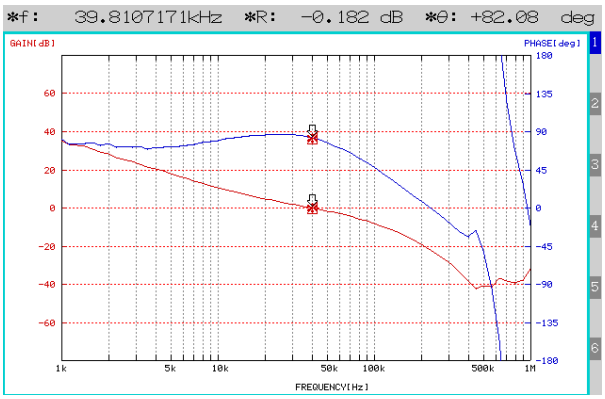

Figure 35. Loop Response
(V_{IN}=12 V, V_{OUT}=3.3 V, I_{OUT}=1 A, C_{OUT}=Ceramic10 µFx3)

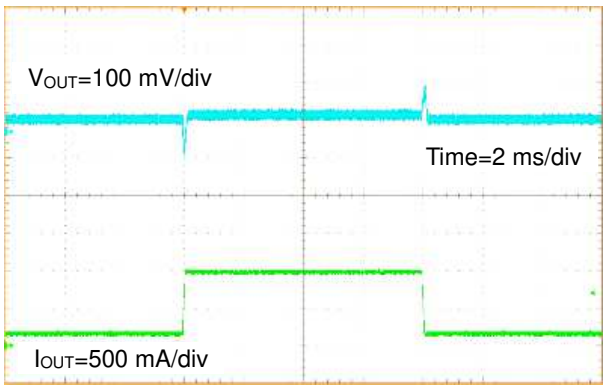

Figure 36. Load Transient Response I_{OUT} =0.2 A – 1 A
(V_{IN}=12 V, V_{OUT}=5 V, C_{OUT}=Ceramic10 µFx3)

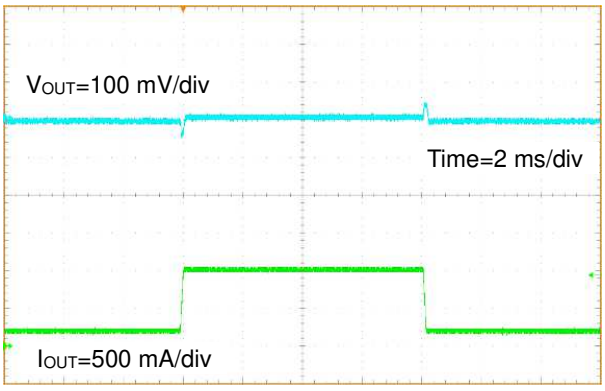

Figure 37. Load Transient Response I_{OUT} =0.2 A – 1 A
(V_{IN}=12 V, V_{OUT}=3.3 V, C_{OUT}=Ceramic10 µFx3)

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Function Description

1. DC/DC converter operation

BD9E104FJ is a synchronous rectifying step-down switching regulator that achieves faster transient response by employing current mode PWM control system. It utilizes switching operation in PWM (Pulse Width Modulation) mode for heavier load, while it utilizes SLLM™ (Simple Light Load Mode) control for lighter load to improve efficiency.

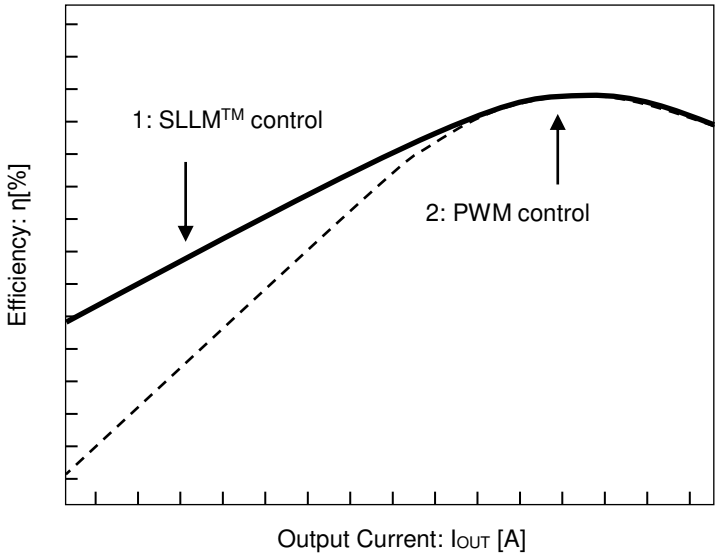

Figure 38. Efficiency (SLLM™ control and PWM control)

1: SLLM™ control

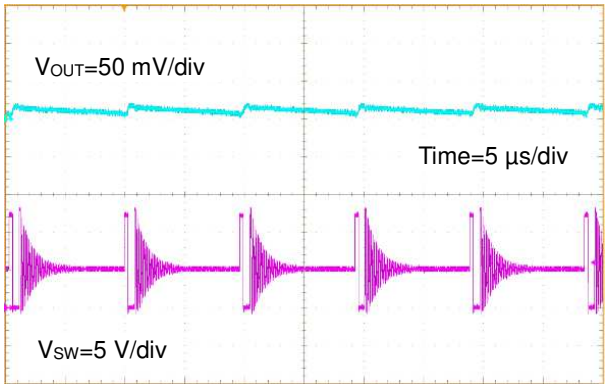

Figure 39. SW Waveform (1: SLLM™ control)
(V_{IN}=12 V, V_{OUT}=5.0 V, I_{OUT}=10 mA)

2: PWM control

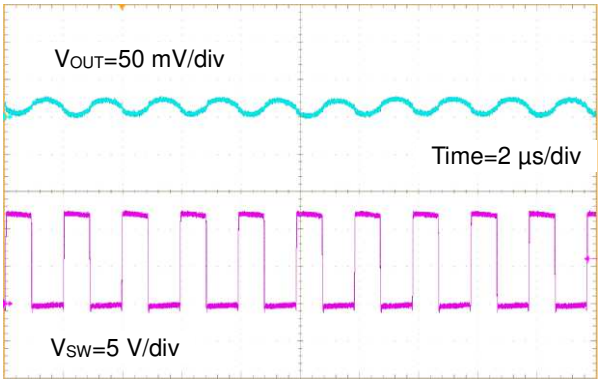

Figure 40. SW Waveform (2: PWM control)
(V_{IN}= 12 V, V_{OUT}=5.0 V, I_{OUT}=1 A)

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Function Description-continued

2. Enable Control

The IC shutdown can be controlled by the voltage applied to the EN pin. When the EN pin voltage reaches 2.5 V (Min), the internal circuit is activated and the IC starts up. To enable shutdown control with the EN pin, set the shutdown interval (Low level interval of EN) must be set to 100 µs or longer.

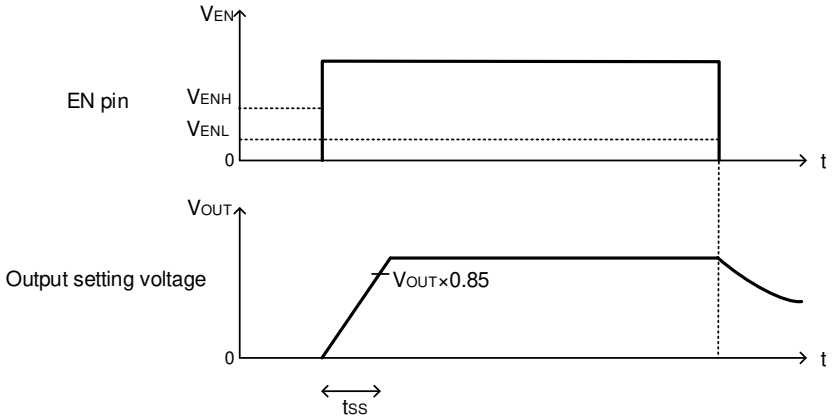

Figure 41. Timing Chart with Enable Control

3. Protective Functions

The protective circuits are intended for prevention of damage caused by unexpected accidents.
Do not use them for continuous protective operation.

(1) Short Circuit Protection (SCP)

The short circuit protection block compares the FB pin voltage with the internal reference voltage VREF. When the FB pin voltage has fallen below 0.56 V (Typ) and remained there for 0.9 ms (Typ), SCP stops the operation for 14.4 ms (Typ) and subsequently initiates a restart.

Table 1. Short Circuit Protection Function

EN pin	FB pin	Short Circuit Protection	Switching Frequency
2.5 V or higher	0.30 V (Typ)≥FB	Enabled	142.5 kHz (Typ)
	0.30 V (Typ)< FB≤0.56 V (Typ)		285 kHz (Typ)
	FB>0.56 V (Typ)		570 kHz (Typ)
0.8 V or lower	-	Disabled	OFF

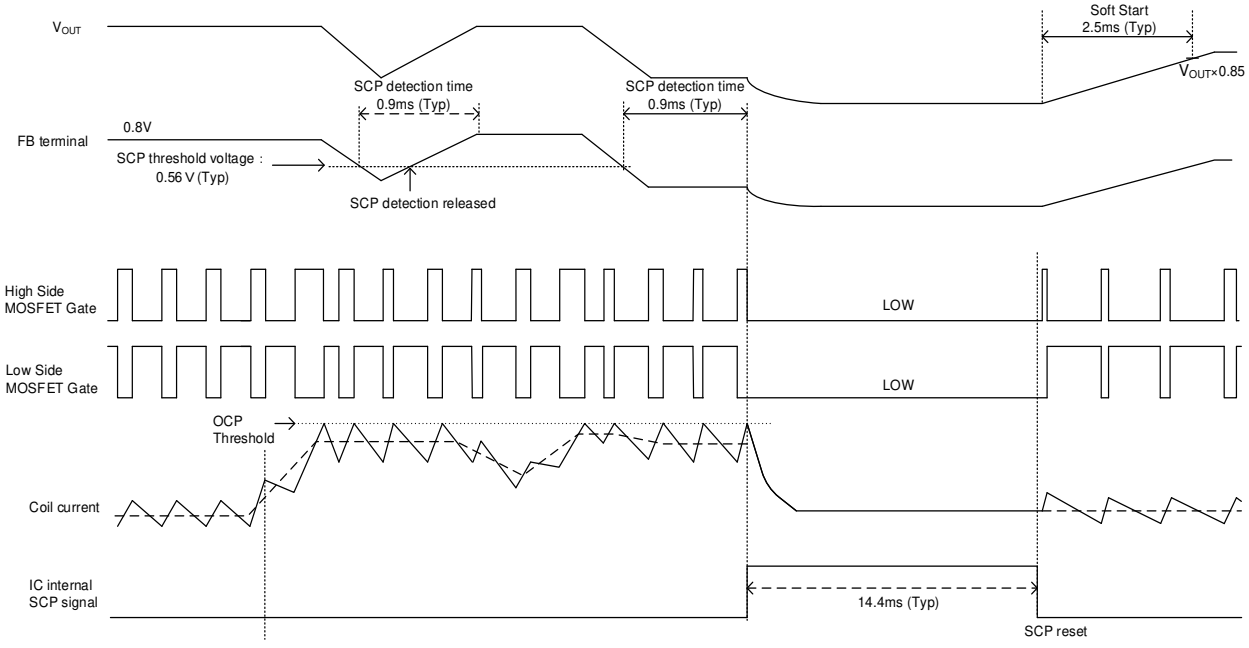

Figure 42. Short Circuit Protection Function (SCP) Timing Chart

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Function Description - continued

(2) Under Voltage Lockout Protection (UVLO)

The under voltage lockout protection circuit monitors the VIN pin voltage.
The operation enters standby when the VIN pin voltage is 6.4 V (Typ) or lower.
The operation starts when the VIN pin voltage is 6.6 V (Typ) or higher.

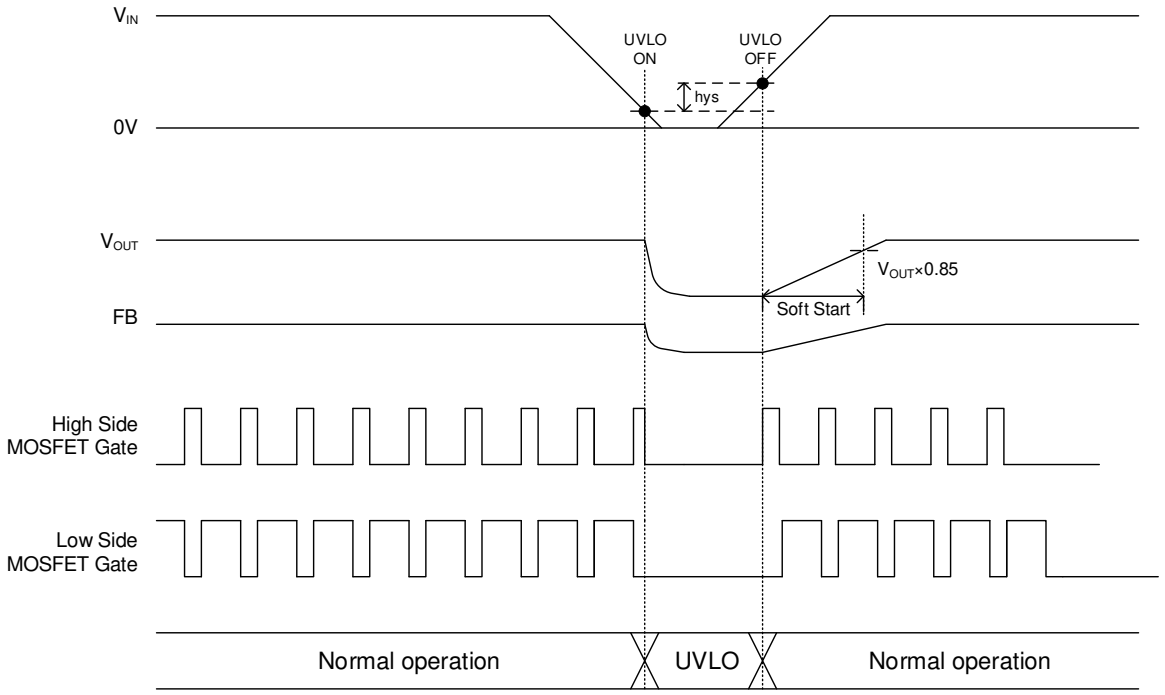

Figure 43. UVLO Timing Chart

(3) Thermal Shutdown Function (TSD)

This is the thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's power dissipation rating. However, if the rating is exceeded for a continued period and the junction temperature (Tj) rises to 175 °C (Typ) or more, the TSD circuit will operate and turn OFF the output MOSFET. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation. Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

(4) Over Current Protection Function (OCP)

The Over Current Protection Function observes the current flowing in High side MOSFET by switching cycle and when it detects over flow current, it limits ON duty and protects by dropping output voltage.

(5) Over Voltage Protection Function (OVP)

Over Voltage Protection Function (OVP) compares the FB pin voltage with internal reference voltage VREF and when the FB pin voltage exceeds 1.04 V (Typ), the OVP function turns off the output MOSFET. When the output voltage drops, the device returns to normal operation with hysteresis.

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Application Example

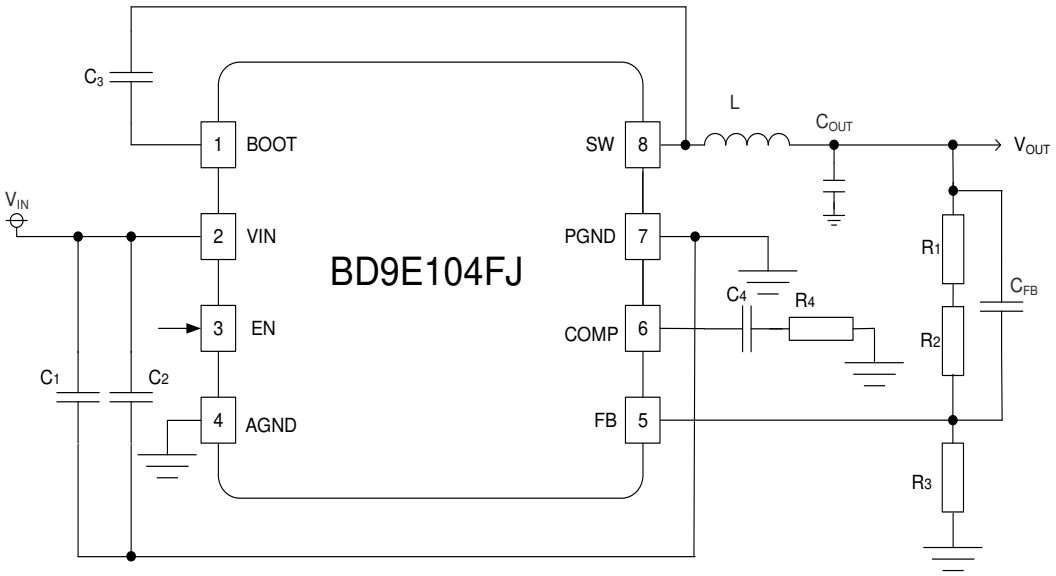

Figure 44. Application Circuit

Table 2. Recommendation Circuit Constants

V_{IN}	12 V		24 V
V_{OUT}	5 V	3.3 V	12 V
C_1 *(Note 1)*	10 µF	10 µF	10 µF
C_2 *(Note 2)*	0.1 µF	0.1 µF	0.1 µF
C_3 *(Note 3)*	0.1 µF	0.1 µF	0.1 µF
L	6.8 µH	6.8 µH	22 µH
R_1	0 Ω	0 Ω	20 kΩ
R_2	430 kΩ	470 kΩ	120 kΩ
R_3	82 kΩ	150 kΩ	10 kΩ
R_4	82 kΩ	56 kΩ	240 kΩ
C_{FB}	12 pF	12 pF	33 pF
C_4	390 pF	470 pF	2200 pF
C_{OUT} *(Note 4)*	Ceramic 10 µF×3	Ceramic 10 µF×3	Ceramic 10 µF×3

(Note 1) For capacitance of input capacitor, take temperature characteristics, DC bias characteristics, etc. into consideration to set minimum value no less than 4.7 µF.
(Note 2) In order to reduce the influence of high frequency noise, arrange the 0.1 µF ceramic capacitor as close as possible to the VIN pin.
(Note 3) Connect a 0.1 µF bootstrap capacitor between the SW pin and the BOOT pin.
(Note 4) In case capacitance value fluctuates due to temperature characteristics, DC bias characteristics, etc. of output capacitor, crossover frequency may fluctuate. When selecting a capacitor, confirm the characteristics of the capacitor in its datasheet. Also, please use ceramic type capacitors for output capacitor.

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Selection of Components Externally Connected

About the application except the recommendation, please contact us.

1. Output LC Filter

The DC/DC converter requires an LC filter for smoothing the output voltage in order to supply a continuous current to the load. In BD9E104FJ, I_L ripple current flowing through the inductor is returned to the IC for SLLM™ control. Use an inductor having the recommended value because the feedback ripple current to the IC is designed to operate optimally when the inductance is the recommended value.

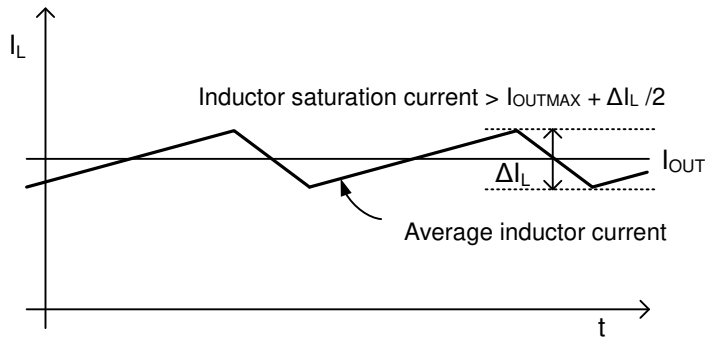

Figure 45. Waveform of Current through Inductor

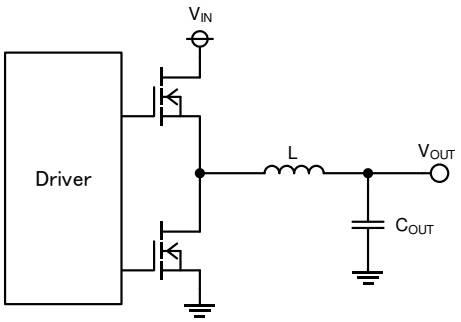

Figure 46. Output LC Filter Circuit

Computation with V_{IN}=12 V, V_{OUT}=5 V, L=6.8 µH, and switching frequency f_{OSC}=570 kHz, the method is as below.

Inductor ripple current

$$\Delta I_L = V_{OUT} \times (V_{IN} - V_{OUT}) \times \frac{1}{V_{IN} \times f_{OSC} \times L} = 752 \text{ [mA]}$$

Also for saturation current of inductor, select the one with larger current than the total of maximum output current and 1/2 of inductor ripple current ΔI_L

Output capacitor C_{OUT} affects output ripple voltage characteristics. Select output capacitor C_{OUT} so that necessary ripple voltage characteristics are satisfied.

Output ripple voltage can be expressed in the following method.

$$\Delta V_{RPL} = \Delta I_L \times (R_{ESR} + \frac{1}{8 \times C_{OUT} \times F_{OSC}}) \quad \text{[V]}$$

R_{ESR} is the serial equivalent series resistance here.

With C_{OUT}=30 µF, R_{ESR}=10 mΩ the output ripple voltage is calculated as below.

$$\Delta V_{RPL} = 0.75 \times (10m + \frac{1}{8 \times 30\mu \times 570k}) = 13 \quad \text{[mV]}$$

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Selection of Components Externally Connected - continued

*Be careful of total capacitance value, when additional capacitor C_{LOAD} is connected to output capacitor C_{OUT}.
Use maximum additional capacitor C_{LOAD} (Max) condition which satisfies the following method.

Maximum starting inductor ripple current I_{L_START} < Over current limit 2.1 A (Min)

Maximum starting inductor ripple current I_{L_START} can be expressed in the following method.

$$I_{L\_START} = \text{Maximum starting output current } (I_{OUTMAX}) + \text{Charge current to output capacitor}(I_{CAP}) + \frac{\Delta I_L}{2}$$

Charge current to output capacitor I_{CAP} can be expressed in the following method.

$$I_{CAP} = \frac{(C_{OUT} + C_{LOAD}) \times V_{OUT}}{t_{SS}} \quad [A]$$

Computation with V_{IN}=12 V, V_{OUT}=5 V, L=6.8 µH, I_{OUTMAX}=1 A (Max), switching frequency f_{OSC}=484 kHz (Min), Output capacitor C_{OUT}=30 µF, Soft Start Time t_{SS}=1.2 ms (Min), the method is as below.

$$C_{LOAD}(Max) \leq \frac{(2.1 - I_{OUTMAX} - \frac{\Delta I_L}{2}) \times t_{SS}}{V_{OUT}} - C_{OUT} = 127 \quad [\mu F]$$

Confirm maximum starting inductor ripple current less than 2.1 A on actual equipment.

2. Output Voltage Set Point

The output voltage value can be set by the feedback resistance ratio.

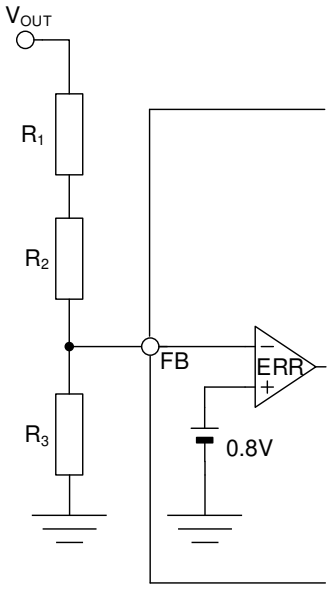

Figure 47. Feedback Resistor Circuit

$$V_{OUT} = \frac{R_1 + R_2 + R_3}{R_3} \times 0.8 \quad [V]$$

*Minimum pulse is 250 ns for BD9E104FJ.
Use input/output condition which satisfies the following method.

$$250ns \leq \frac{V_{OUT}}{V_{IN}} \times 1.75 \quad [\mu s]$$

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Selection of Components Externally Connected - continued

3. Phase Compensation

A current mode control buck DC/DC converter is a two-pole, one-zero system. Two-pole formed by an error amplifier and load and one zero point added by phase compensation. The phase compensation resistor R_4 determines the crossover frequency f_{CRS} where the total loop gain of the DC/DC converter is 0 dB. High value for this crossover frequency f_{CRS} provides a good load transient response characteristic but inferior stability. Conversely, specifying a low value for the crossover frequency f_{CRS} greatly stabilizes the characteristics but the load transient response characteristic is impaired.

(1) Selection of Phase Compensation Resistor R_4

The phase compensation resistance R_4 can be determined by using the following equation.

$$R_4 = \frac{2\pi \times V_{OUT} \times f_{CRS} \times C_{OUT}}{V_{FB} \times G_{MP} \times G_{MA}} \quad [\Omega]$$

Where:

V_{OUT} is the output voltage (5 V (Typ))
f_{CRS} is the crossover frequency [Hz]
C_{OUT} is the output capacitance [F]
V_{FB} is the feedback reference voltage (0.8 V (Typ))
G_{MP} is the current sense gain (7 A/V (Typ))
G_{MA} is the error amplifier transconductance (82 µA/V (Typ))

(2) Selection of phase compensation capacitance C_4

For stable operation of the DC/DC converter, inserting a zero point at 1/6 of the zero crossover frequency cancels the phase delay due to the pole formed by the load often provides favorable characteristics.

The phase compensation capacitance C_4 can be determined by using the following equation.

$$C_4 = \frac{1}{2\pi \times R_4 \times f_Z} \quad [F]$$

Where:

f_Z is Zero point inserted

(3) Loop stability

In order to ensure stability of DC/DC converter, confirm there is enough phase margin on actual equipment. Under the worst condition, it is recommended to ensure phase margin is 45° or more. The feed forward capacitor C_{FB} is used for the purpose of forming a zero point together with the resistor R_1 and R_2 to increase the phase margin within the limited frequency range.

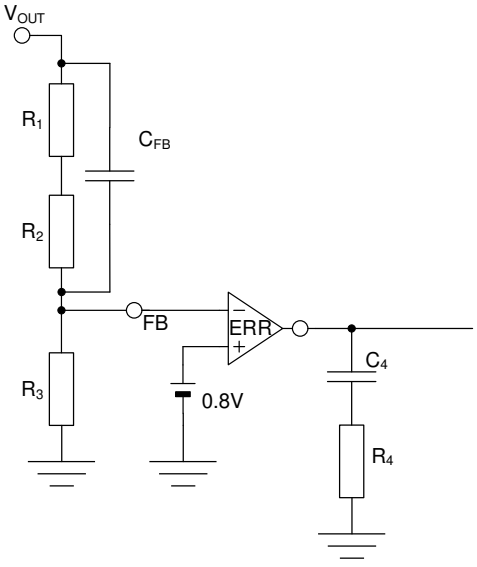

Figure 48. Phase Compensation Circuit

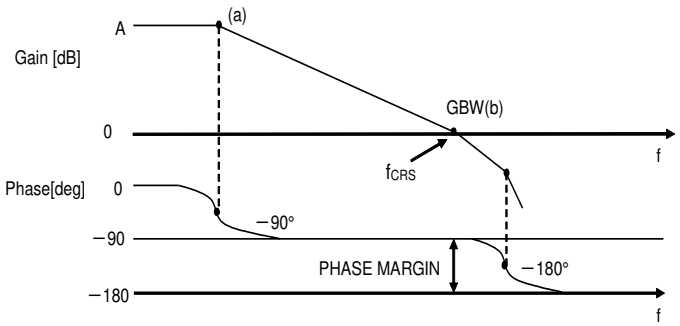

Figure 49. Bode Plot

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PCB Layout Design

PCB layout design for DC/DC converter power supply IC is as important as the circuit design. Appropriate layout can avoid various problems caused by power supply circuit. Figure 50-a to 50-c show the current path in a buck DC/DC converter circuit. The Loop1 in Figure 50-a is a current path when High Side switch is ON and Low Side switch is OFF, the Loop2 in Figure 50-b is when High Side switch is OFF and Low Side switch is ON. The thick line in Figure 50-c shows the difference between Loop1 and Loop2. The current in thick line changes sharply each time the switching element High Side and Low Side switch change from OFF to ON, and vice versa. These sharp changes induce several harmonics in the waveform. Therefore, the loop area of thick line that is consisted by input capacitor and IC should be as small as possible to minimize noise. For more detail, refer to application note of switching regulator series “PCB Layout Techniques of Buck Converter”.

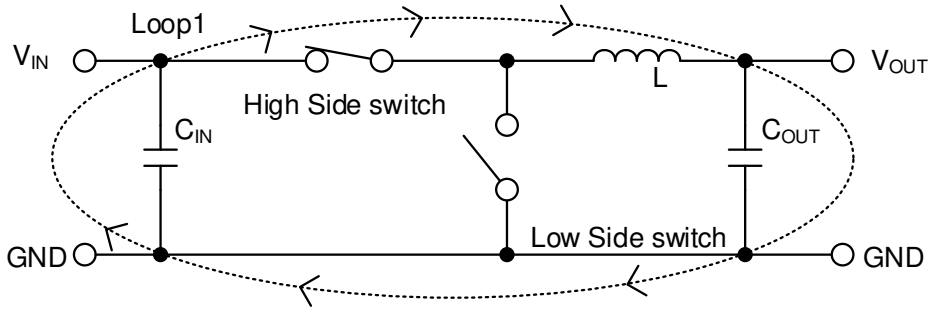

Figure 50-a. Current path when High Side switch = ON, Low Side switch = OFF

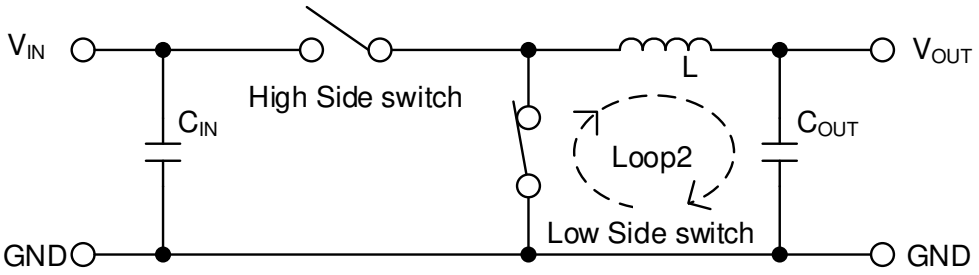

Figure 50-b. Current Path when High Side switch = OFF, Low Side switch = ON

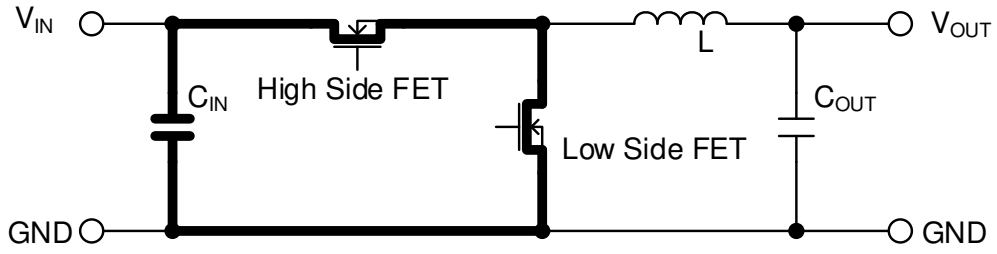

Figure 50-c. Difference of Current and Critical Area in Layout

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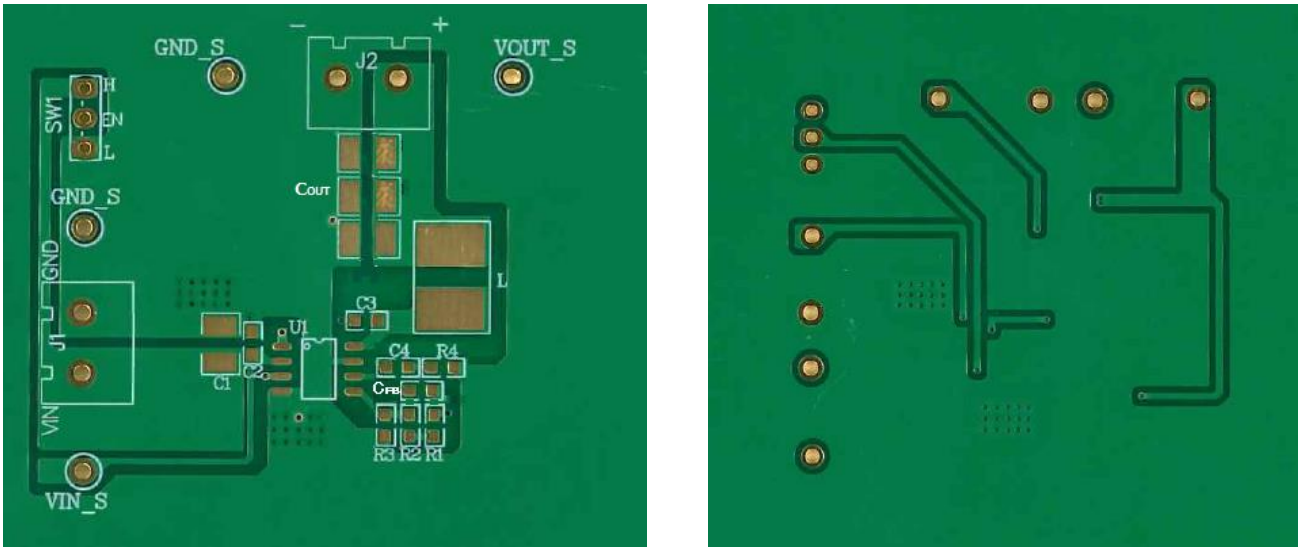
PCB Layout Design - continued

Accordingly, design the PCB layout with particular attention paid to the following points.

- Provide the input capacitor close to the VIN pin of the IC as possible on the same plane as the IC.
- If there is any unused area on the PCB, provide a copper foil plane for the ground node to assist heat dissipation from the IC and the surrounding components.
- Switching nodes such as SW are susceptible to noise due to AC coupling with other nodes. Trace to the coil as thick and short as possible.
- Provide lines connected to the FB pin and the COMP pin as far from the SW node.
- Provide the output capacitor away from the input capacitor in order to avoid the effect of harmonic noise from the input.



Top Layer Bottom Layer

Figure 51. Example of Sample Board Layout Pattern

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I/O Equivalence Circuit

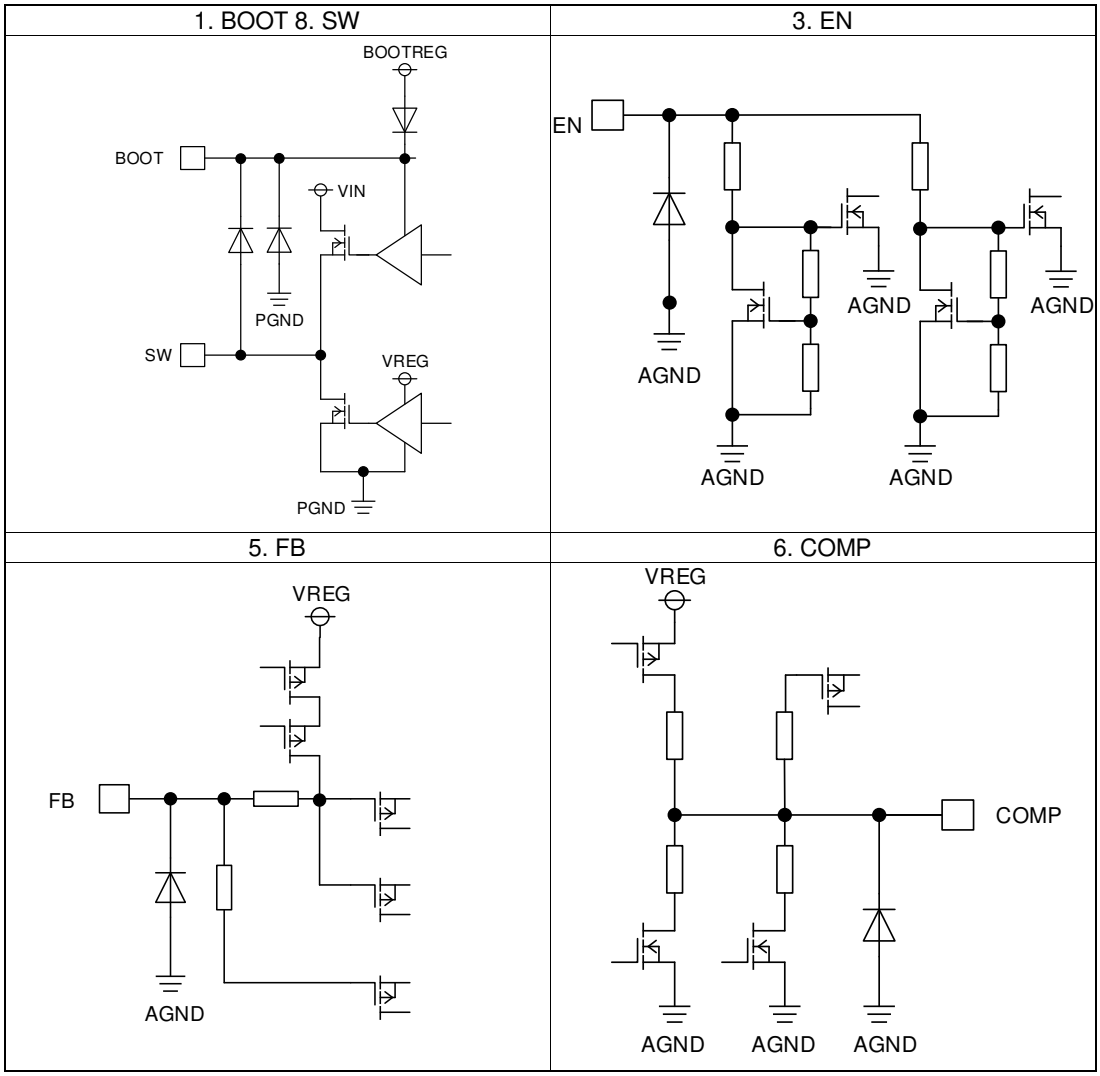

Figure 52. I/O Equivalence Circuit

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